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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/998,469	11/29/2001	Narayan Solayappan	13176.403	5686
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PATTON BO	GGS			
PO BOX 27093			EXAMI	NER
		PERALTA,	ALTA, GINETTE	
			ART UNIT	PAPER NUMBER
			2814	···
	DATE MAILED: 01/29/2003			

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)	1
-	09/998,469	SOLAYAPPAN ET AL.	
Office Action Summary	Examiner	Art Unit	
	Ginette Peralta	2814	
The MAILING DATE of this communication app	pears on the cover sheet	with the correspondence addres	s
Period for Reply	VIC SET TO EYDIDE 3	MONTH(S) FROM	
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a repl - If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by statute - Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, man	r a reply be timely filed thirty (30) days will be considered timely. MONTHS from the mailing date of this commu	nication.
Status  1) Responsive to communication(s) filed on 16.	January 2003 .		
, —	his action is non-final.		
24) 11110 desire to the term of the term o		natters, prosecution as to the m	erits is
3) Since this application is in condition for allow closed in accordance with the practice under Disposition of Claims	Ex parte Quayle, 1935	C.D. 11, 453 O.G. 213.	
4)⊠ Claim(s) <u>1-46</u> is/are pending in the applicatio	n.		
4a) Of the above claim(s) is/are withdra	wn from consideration.		
5) Claim(s) is/are allowed.			
6)⊠ Claim(s) <u>1-46</u> is/are rejected.			
7) Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction and/	or election requirement.		
Application Papers			
9) The specification is objected to by the Examin			
10)☐ The drawing(s) filed on is/are: a)☐ acce			
Applicant may not request that any objection to the			
11) The proposed drawing correction filed on		disapproved by the Examiner.	
If approved, corrected drawings are required in re	eply to this Office action.		
12) The oath or declaration is objected to by the E	xaminer.		
Priority under 35 U.S.C. §§ 119 and 120			
13) Acknowledgment is made of a claim for foreign	gn priority under 35 U.S	.C. § 119(a)-(d) or (f).	
a) ☐ All b) ☐ Some * c) ☐ None of:			
1. Certified copies of the priority documer	nts have been received.		
2. Certified copies of the priority documer	nts have been received	in Application No	
3. Copies of the certified copies of the pri application from the International B * See the attached detailed Office action for a lis	Bureau (PCT Rule 17.2(	a)).	ige
14) Acknowledgment is made of a claim for domes			plication).
a) The translation of the foreign language p  15) Acknowledgment is made of a claim for dome	rovisional application ha	as been received.	
Attachment(s)			
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) 🔲 Notic	view Summary (PTO-413) Paper No(s). re of Informal Patent Application (PTO-1 r:	52)

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## **DETAILED ACTION**

## Election/Restrictions

1. Claims 47-67 withdrawn from further consideration pursuant to 37 CFR 1.142(b) as being drawn to a nonelected invention, there being no allowable generic or linking claim. Election was made without traverse in Paper No. 5.

## Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (a) the invention was known or used by others in this country, or patented or described in a printed publication in this or a foreign country, before the invention thereof by the applicant for a patent.
- (e) the invention was described in-
- (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effect under this subsection of a national application published under section 122(b) only if the international application designating the United States was published under Article 21(2)(a) of such treaty in the English language; or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that a patent shall not be deemed filed in the United
- invention by the applicant for patent, except that a patent shall not be deemed filed in the United States for the purposes of this subsection based on the filing of an international application filed under the treaty defined in section 351(a).
- 3. Claims 1-4, 11-12, 19-22, 28-30, 36 are rejected under 35 U.S.C. 102(e) as being anticipated by Kanaya (US Pat. Pub. 2002/0038402 A1).

Kanaya discloses in Fig. 31B an integrated circuit comprising a thin film of metal oxide material 304; and a hydrogen barrier layer 402 located to inhibit the diffusion of hydrogen to the metal oxide material, selected from the group comprising titanium oxide, zirconium oxide and aluminum oxide, among others.

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Regarding claim 2, Kanaya discloses that the metal oxide 304 comprises a perovskite ( $\P[0178]$ ).

Regarding claim 3, Kanaya discloses that the metal oxide comprises lead zirconium titanate (PZT), an inherent property of this material is having a dielectric constant of 20 or more.

Regarding claim 4, Kanaya discloses that the metal oxide comprises a ferroelectric material, lead zirconium titanate (PZT).

Regarding claim 11, Kanaya further discloses a capacitor having a first electrode 303 and a second electrode 305, and the metal oxide material 304 is located between the first and second electrodes.

Regarding claim 12, Kanaya discloses the capacitor being a ferroelectric capacitor, and the metal oxide being a ferroelectric material.

Regarding claim 19, Kanaya discloses the hydrogen barrier layer material being amorphous.

Regarding claim 20, Kanaya discloses the integrated circuit including a semiconducting substrate 1, and the metal oxide 304 is located between the hydrogen barrier layer and the substrate.

Regarding claim 21, Kanaya discloses in Fig. 32, the integrated circuit including a wiring layer 306c and a second hydrogen barrier layer 403 located above the wiring.

Regarding claim 22, Kanaya discloses in Fig. 32, the integrated circuit including a substrate 301, and a wiring layer 306c, the metal oxide material 304 being located

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between the wiring layer and the substrate, and the hydrogen barrier layer 403 located above the wiring layer.

Regarding claim 28, Kanaya discloses in Fig. 32, an integrated circuit comprising a thin film of metal oxide material 304 and a hydrogen barrier layer 402 located to inhibit the diffusion of hydrogen to the metal oxide material, the hydrogen barrier layer comprising an amorphous material.

Regarding claim 29, Kanaya discloses the integrated circuit comprising a capacitor having a first electrode 303 and a second electrode 305, and the metal oxide is located between the first and second electrodes.

Regarding claim 30, Kanaya discloses that the metal oxide comprises a ferroelectric material, lead zirconium titanate (PZT).

Regarding claim 36, Kanaya discloses the use of PZT, which inherently has a crystallization temperature greater than 650°C.

4. Claims 38-44 and 46 are rejected under 35 U.S.C. 102(a) as being anticipated by Amanuma (U. S. Pat. 6,188,098 B1).

Regarding claim 38, Amanuma discloses in Fig. 20 an integrated circuit comprising a thin film of metal oxide material 9; and a hydrogen barrier layer located to inhibit the diffusion of hydrogen to the metal oxide material 9, the hydrogen barrier layer comprising a primary hydrogen barrier layer material (7 or 11) and a supplemental hydrogen barrier layer material 12; the primary hydrogen barrier layer

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material being different than the supplemental hydrogen barrier material, and wherein the primary and supplemental materials are either both conducting or both insulating.

Regarding claim 39, Amanuma discloses that the supplemental material 12 is located in contact with the primary material 11.

Regarding claim 40, Amanuma discloses that the primary material and the secondary material are both conducting when referring to the layers 11 and 12, as shown in col. 8, ll. 38-60.

Regarding claim 41, Amanuma discloses a primary material 7 and a secondary material 12, wherein both are insulating, as shown in col. 6, ll. 19-67.

Regarding claim 42, Amanuma discloses a primary material 11 that is more compatible with the metal oxide 9 and is located closer to the metal oxide material.

Regarding claim 43, Amanuma discloses the primary material comprising one of the chemical elements that is in the metal oxide material, as shown by the use of SBT or PZT for the metal oxide, and titanium nitride or tantalum nitride for the hydrogen barrier layer.

Regarding claim 44, Amanuma discloses the use of SBT, which is a superlattice material.

Regarding claim 46, Amanuma discloses that the supplemental material comprises silicon nitride.

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## Claim Rejections - 35 USC § 103

- 5. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 6. Claims 5-8, 13, 17, 18, 23-27, 31, 35, 37 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kanaya in view of Amanuma (U. S. Pat. 6,188,098 B1).

With regards to claims 5-8, 13, 31, Kanaya as applied above discloses the claimed invention with the exception of metal oxide comprising a layered superlattice material.

Amanuma discloses in Fig. 1 an integrated circuit comprising a thin film of metal oxide material 9; and a hydrogen barrier layer (7, 11, 12) located to inhibit the diffusion of hydrogen to the metal oxide material, the metal oxide comprising one of strontium bismuth tantalate(SBT) or lead zirconium titanate(PZT), where the SBT and the PZT are used as alternatives, and the SBT is a layered superlattice material.

Thus, it would have been obvious to one having ordinary skill in the art at the time the invention was made to use either strontium bismuth tantalate or lead zirconium titanate, since it has been held to be within the general skill of a worker in the art to select a known material on the basis of its suitability for the intended use as a matter of obvious design choice. In re Leshin, 125 USPQ 416.

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With regards to claims 17, 18, 35, and 37, Amanuma discloses in col. 6, Il. 52-53, the hydrogen barrier layer having a thickness of 100 Å. It would have been an obvious matter of design choice to vary the thickness of the hydrogen barrier layer, since such a modification would have involved a mere change in the size of a component. A change in size is generally recognized as being within the level of ordinary skill in the art. In re Rose, 105 USPQ 237 (CCPA 1955).

With regards to claims 23, 24, 25, 26, 27, Kanaya discloses the claimed invention with the exception of the hydrogen barrier layer comprising a primary and a supplemental hydrogen barrier layer.

Amanuma discloses a hydrogen barrier layer comprising a primary hydrogen barrier layer 11 and a supplemental hydrogen barrier layer 12 different from the primary hydrogen barrier layer, wherein the supplemental barrier layer is used for the disclosed intended purpose of encapsulating the capacitor portion and preventing the deterioration of the ferroelectric metal oxide, and further teaches the supplemental hydrogen barrier layer comprising silicon nitride, or titanium nitride.

Thus, it would have been obvious to one of ordinary skill in the art at the time the invention was made to use a supplemental hydrogen barrier layer in the invention of Kanaya for the disclosed intended purpose of Amanuma of encapsulating the capacitor portion and preventing the deterioration of the ferroelectric metal oxide.

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7. Claims 9 and 10 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kanaya in view of Amanuma and further in view of Shimida et al. (U. S. Pat. 6,351,004 B1).

Kanaya as modified by Amanuma above discloses the claimed invention with the exception of the hydrogen barrier layer comprising one of strontium tantalite, bismuth tantalite, or tantalum oxide.

Shimida discloses an integrated circuit comprising a thin film of metal oxide material 6, and a hydrogen barrier film that comprises one of silicon oxide, strontium tantalate or strontium titanate, wherein one of these materials is used for the disclosed intended purpose of preventing the oxidation of the conductive layers surrounding the metal oxide material.

Thus, it would have been within the scope of one of ordinary skill in the art at the time the invention was made to use other materials for the hydrogen barrier material and take advantage of other benefits like the disclosed intended purpose of Shimida of preventing the oxidation of the layers that make contact with the ferroelectric material, since it has been held to be within the general skill of a worker in the art to select a known material on the basis of its suitability for the intended use as a matter of obvious design choice. In re Leshin, 125 USPQ 416.

8. Claims 14-16 and 32-35 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kanaya in view of Shimida et al..

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Kanaya discloses the claimed invention with the exception of the integrated circuit comprising a field effect transistor having a substrate and a gate electrode and the metal oxide material being located between the substrate and the gate electrode.

Shimida discloses in fig. 5 an integrated circuit comprising a field effect transistor comprising a substrate 1 and a gate electrode 7, and the metal oxide material 6 being located between the substrate and the gate electrode; wherein the FET is a ferroelectric FET and the metal oxide comprises a ferroelectric material, and further a superlattice material.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Ginette Peralta whose telephone number is (703)305-7722. The examiner can normally be reached on Monday to Friday 8:00 AM- 5:30 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael Fahmy can be reached on (703)308-4918. The fax phone numbers for the organization where this application or proceeding is assigned are (703)308-7722 for regular communications and (703)308-7724 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703)308-0956.

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GP January 27, 2003

SUPERVISORY PRIMARY EMAMINER
TECHNOLOGY CENTER 2800